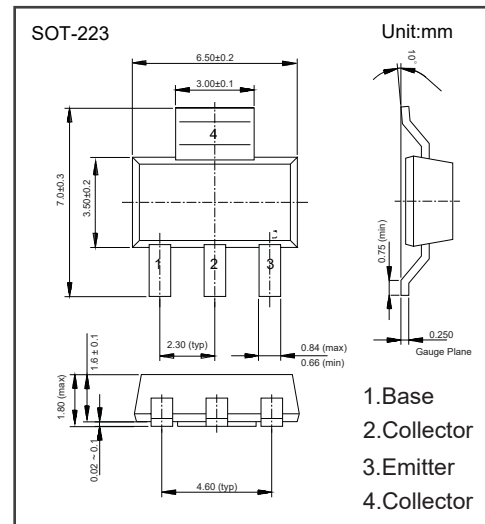




■ Features

- Collector Current Capability $I_C = -4A$
- Collector Emitter Voltage $V_{CE0} = -140V$
- Very low saturation voltages



■ Absolute Maximum Ratings $T_a = 25^\circ C$

Parameter	Symbol	Rating	Unit
Collector - Base Voltage	V_{CBO}	-180	V
Collector - Emitter Voltage	V_{CEO}	-140	
Emitter - Base Voltage	V_{EBO}	-6	
Collector Current - Continuous	I_C	-4	A
Peak Pulse Current	I_{CM}	-10	
Collector Power Dissipation	P_C	3	W
Thermal Resistance, Junction to Ambient (Note 1)	$R_{\theta JA}$	42	$^\circ C/W$
Operating and Storage Temperature Range	T_J, T_{stg}	-55 to 150	$^\circ C$

Note 1: For a device mounted with the collector lead on 52mm x 52mm 2oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in steady-state.



■ Electrical Characteristics Ta = 25°C

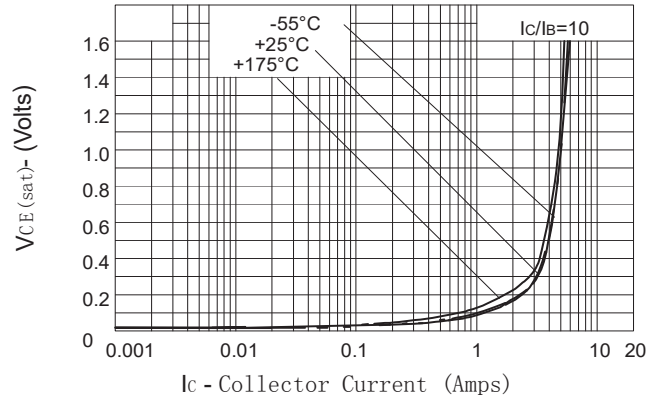
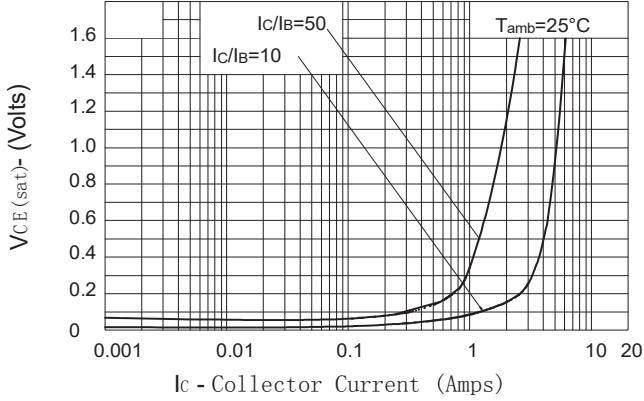
Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Collector- base breakdown voltage	VCBO	Ic= -100 μA, IE=0	-180			V
Collector- emitter breakdown voltage	VCER	Ic=-1 μA, RB ≤ 1kΩ	-180			
Collector- emitter breakdown voltage	VCEO	Ic= -10 mA, IB=0	-140			
Emitter - base breakdown voltage	VEBO	IE= -100 μA, IC=0	-6			
Collector-base cut-off current	ICBO	VCB= -150 V, IE=0			-50	nA
		VCB= -150 V, IE=0, Ta = 100°C			-1	μA
Collector cut-off current R < 1kΩ	ICER	VCE= -150 V, IE=0			-50	nA
		VCE= -150 V, IE=0, Ta = 100°C			-1	μA
Emitter cut-off current	IEBO	VEB= -6V, IC=0			-10	nA
Collector-emitter saturation voltage	VCE(sat)	Ic=-100 mA, IB=-5 mA			-60	mV
		Ic=-500 mA, IB=-50mA			-120	
		Ic=-1 A, IB=-100mA			-150	
		Ic=-3 A, IB=-300mA			-370	
Base - emitter saturation voltage	VBE(sat)	IC=-3 A, IB=-300mA			-1110	
Base - emitter turn-on voltage	VBE(on)	VCE= -5V, IC= -3A			-950	
DC current gain	hFE	VCE= -5V, IC= -10mA	100			
		VCE=- 5V, IC= -1 A	100		300	
		VCE= -5V, IC= -3 A	75			
		VCE= -5V, IC= -10 A		10		
Switching Times	t _{on}	Ic=-1A, IB1=-100mA		68		ns
	t _{off}	IB2=100mA, VCC=-50V		1030		
Collector output capacitance	Cob	VCB= -20V, f=1MHz		40		pF
Transition frequency	fr	VCE= -10V, IC= -100mA, f=50MHz		110		MHz

Note : Measured under pulsed conditions. Pulse width ≤ 300 us. Duty cycle ≤ 2%

■ Marking

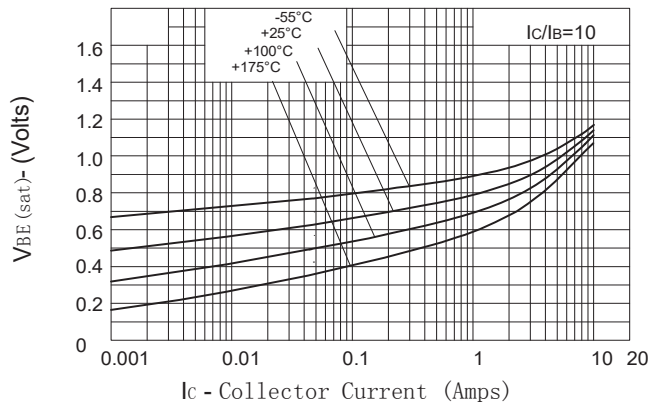
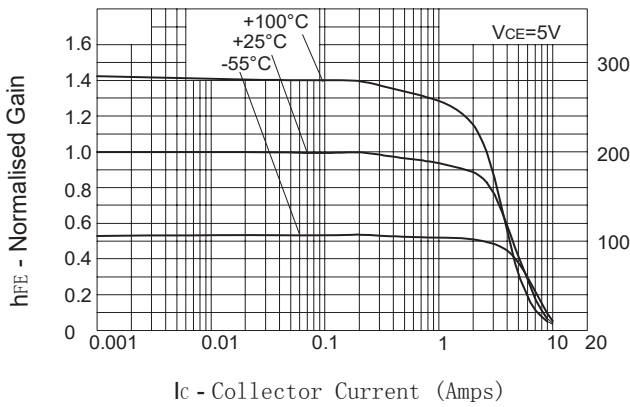
Marking	FZT955 ****
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Typical Characteristics



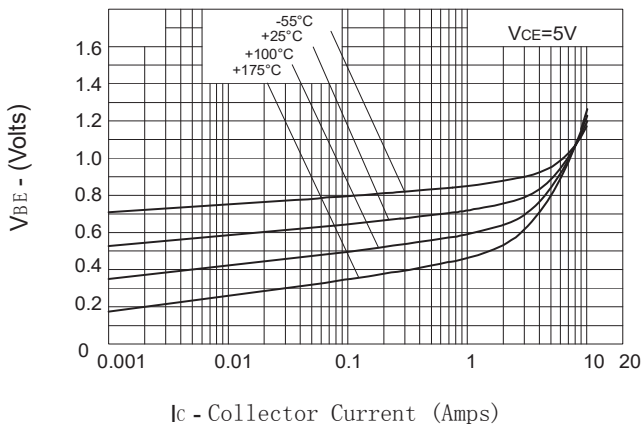
VCE(sat) v IC

VCE(sat) v IC

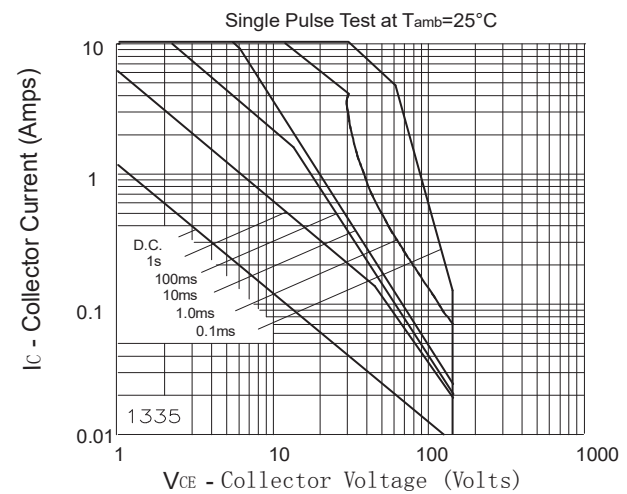


hFE v IC

VBE(sat) v IC



VBE(on) v IC



Safe Operating Area

Package	Reel	Reel Size	Box	Box Size(mm)	Carton	Carton Size(mm)
SOT -223	2500pcs	13inch	2500pcs	336x336x48	20,000pcs	445x355x365